

LM194/LM394 Supermatch Pair

General Description

The LM194 and LM394 are junction isolated ultra wellmatched monolithic NPN transistor pairs with an order of magnitude improvement in matching over conventional transistor pairs. This was accomplished by advanced linear processing and a unique new device structure.

Electrical characteristics of these devices such as drift versus initial offset voltage, noise, and the exponential relationship of base-emitter voltage to collector current closely approach those of a theoretical transistor. Extrinsic emitter and base resistances are much lower than presently available pairs, either monolithic or discrete, giving extremely low noise and theoretical operation over a wide current range. Most parameters are guaranteed over a current range of 1 μ A to 1 mA and 0V up to 40V collector-base voltage, ensuring superior performance in nearly all applications.

To guarantee long term stability of matching parameters, internal clamp diodes have been added across the emitterbase junction of each transistor. These prevent degradation due to reverse biased emitter current—the most common cause of field failures in matched devices. The parasitic isolation junction formed by the diodes also clamps the substrate region to the most negative emitter to ensure complete isolation between devices.

The LM194 and LM394 will provide a considerable improvement in performance in most applications requiring a closely matched transistor pair. In many cases, trimming can be eliminated entirely, improving reliability and decreasing costs. Additionally, the low noise and high gain make this device attractive even where matching is not critical.

The LM194 and LM394/LM394B/LM394C are available in an isolated header 6-lead TO-5 metal can package. The LM394/LM394B/LM394C are available in an 8-pin plastic dual-in-line package. The LM394C is also available in a 8 pin plastic dual-in-line package. The LM194 is identical to the LM394 except for tighter electrical specifications and wider temperature range.

Features

- Emitter-base voltage matched to 50 µV
- Offset voltage drift less than 0.1 µV/°C
- Current gain (hFE) matched to 2%
- Common-mode rejection ratio greater than 120 dB
- Parameters guaranteed over 1 µA to 1 mA collector current
- Extremely low noise
- Superior logging characteristics compared to conventional pairs
- Plug-in replacement for presently available devices

Typical Applications



LM194/LM394

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

(Note 4)	
Collector Current	20 mA
Collector-Emitter Voltage	VMAX
Collector-Emitter Voltage	40V
LM394C	20V
Collector-Base Voltage	40V
LM394C	20V
Collector-Substrate Voltage	40V
LM394C	20V
Collector-Collector Voltage	40V
LM394C	20V

Base-Emitter Current	± 10 mA
Power Dissipation	500 mW
Junction Temperature	
LM194	-55°C to +125°C
LM394/LM394B/LM394C	-25°C to +85°C
Storage Temperature Range	-65°C to +150°C
Soldering Information	
Metal Can Package (10 sec.)	260°C
Dual-In-Line Package (10 sec.)	260°C
Small Outline Package	
Vapor Phase (60 sec.)	215°C
Infrared (15 sec.)	220°C
See AN-450 "Surface Mounting and	their Effects on Prod-

uct Reliability' for other methods of soldering surface mount devices.

Electrical Characteristics (T_J = 25°C)

Parameter	Conditions	{	LM194	ļ į		LM394		LM	394B/3	94C	Units
	Conditions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Current Gain (h _{FE})	$\begin{split} V_{CB} &= 0V \text{ to } V_{MAX} \text{ (Note 1)} \\ I_{C} &= 1 \text{ mA} \\ I_{C} &= 100 \ \mu\text{A} \\ I_{C} &= 10 \ \mu\text{A} \\ I_{C} &= 1 \ \mu\text{A} \end{split}$	500 400 300 200	700 550 450 300		300 250 200 150	700 550 450 300		225 200 150 100	500 400 300 200		
Current Gain Match, (h _{FE} Match) $100 [\Delta I_B] [h_{FE(MIN)}]$ I_C	$V_{CB} = 0V \text{ to } V_{MAX}$ $I_{C} = 10 \ \mu\text{A to 1 mA}$ $I_{C} = 1 \ \mu\text{A}$		0.5 1.0	2		0.5 1.0	4		1.0 2.0	5	% %
Emitter-Base Offset Voltage	$V_{CB} = 0$ $I_C = 1 \ \mu A \text{ to } 1 \ mA$		25	50		25	150		50	200	μV
Change in Emitter-Base Offset Voltage vs Collector-Base Voltage (CMRR)	(Note 1) $I_C = 1 \ \mu A$ to 1 mA, $V_{CB} = 0V$ to V_{MAX}		10	25		10	50		10	100	μV
Change in Emitter-Base Offset Voltage vs Collector Current	$V_{CB} = 0V,$ $I_C = 1 \ \mu A \text{ to } 0.3 \text{ mA}$		5	25		5	50		5	50	μV
Emitter-Base Offset Voltage Temperature Drift	$I_{C} = 10 \ \mu A \text{ to } 1 \text{ mA} \text{ (Note 2)}$ $I_{C1} = I_{C2}$ V_{OS} Trimmed to 0 at 25°C		0.08 0.03	0.3 0.1		0.08 0.03	1.0 0.3		0.2 0.03	1.5 0.5	μV/°C μV/°C
Logging Conformity	$I_{\rm C} = 3 \text{ nA to } 300 \ \mu\text{A},$ $V_{\rm CB} = 0, \text{ (Note 3)}$		150			150			150		μV
Collector-Base Leakage	$V_{CB} = V_{MAX}$		0.05	0.25		0.05	0.5		0.05	0.5	nA
Collector-Collector Leakage	V _{CC} = V _{MAX}		0.1	2.0		0.1	5.0		0.1	5.0	nA
Input Voltage Noise	$I_{\rm C} = 100 \ \mu {\rm A}, V_{\rm CB} = 0 {\rm V},$ f = 100 Hz to 100 kHz		1.8			1.8			1.8		nV/√Hz
Collector to Emitter Saturation Voltage	$I_{C} = 1 \text{ mA}, I_{B} = 10 \mu \text{A}$ $I_{C} = 1 \text{ mA}, I_{B} = 100 \mu \text{A}$		0.2 0.1			0.2 0.1			0.2 0.1		v v

Note 1: Collector-base voltage is swept from 0 to V_{MAX} at a collector current of 1 μ A, 10 μ A, 100 μ A, and 1 mA.

Note 2: Offset voltage drift with $V_{OS} = 0$ at $T_A = 25^{\circ}C$ is valid only when the ratio of I_{C1} to I_{C2} is adjusted to give the initial zero offset. This ratio must be held to within 0.003% over the entire temperature range. Measurements taken at $+25^{\circ}C$ and temperature extremes.

Note 3: Logging conformity is measured by computing the best fit to a true exponential and expressing the error as a base-emitter voltage deviation.

Note 4: Refer to RETS194X drawing of military LM194H version for specifications.



Typical Applications (Continued)

Precision Low Drift Operational Amplifier



High Accuracy One Quadrant Multiplier/Divider



LM194/LM394

Typical Applications (Continued) **High Performance Instrumentation Amplifier** O 15V Rt R2 **80k** 0.1% **₹** 80k 2 6 LM108 O OUTPUT C1 50 pF LM194 R11 Ş 18k INPUTS 0.1% Rs R3 18k 0.1% LM394 8.2M 5% R10 R4 ξ 2k ~~ 2k 0.1% R20 0.1% 100k 0.1% R5 2k 5% LM194 106 Bs *Gain = R6 4k R7 D1 **R**8 5% ξ R9 ş LM113 10k 10k 50 0 1% 1.2V 0 1% CERMET D2 1N457 -15V 7 TL/H/9241-7 **Performance Characteristics** G = 10,000 G = 1,000 G = 100 G = 10Linearity of Gain (±10V Output) ≤0.01 ≤0.01 ≤0.02 ≤0.05 % Common-Mode Rejection Ratio (60 Hz) ≥ 120 ≥110 ≥90 dB ≥120 Common-Mode Rejection Ratio (1 kHz) ≥110 ≥110 ≥90 ≥70 dB Power Supply Rejection Ratio + Supply >110 >110 >110 >110 dB - Supply >110 >110 >90 >70 dB Bandwidth (-3 dB) 50 50 50 50 kHz Slew Rate 0.3 0.3 0.3 0.3 V/µs ≤0.4 ≤10 Offset Voltage Drift** ≤0.25 2 μV/°C Common-Mode Input Resistance >109 > 109 >109 > 109 Ω $>3 \times 10^8 > 3 \times 10^8 > 3 \times 10^8$ Differential Input Resistance >3 x 108 Ω n۷ Input Referred Noise (100 Hz \leq f \leq 10 kHz) 5 6 12 70 √Hz Input Bias Current 75 75 75 75 'nΑ Input Offset Current 1.5 1.5 1.5 1.5 nA Common-Mode Range ±11 ±10 ٧ ±11 ±11 v Output Swing ($R_L = 10 k\Omega$) ±13 ±13 ±13 ±13 **Assumes ≤ 5 ppm/°C tracking of resistors

Typical Performance Characteristics



1

100 H

1

10 100

> 40 50

TL/H/9241-8

10



LM194/LM394

5-25

Connection Diagram

LM194/LM394



Dual-In-Line and Small Outline Packages



Order Number LM394CM, LM394N, LM394BN or LM394CN See NS Package Number M08A or N08E

